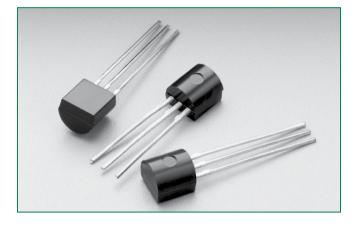


TCR22-x Series RoHS



Description

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Sensitive gate SCRs are easily triggered with microAmps of current as furnished by sense coils, proximity switches, and microprocessors.

Features & Benefits

- RoHS compliant
- Glass passivated junctions
- Voltage capability up to 600 V
- Surge capability up to 20 A

Main Features

Symbol	Value	Unit	
I _{T(RMS)}	1.5	А	
V _{DRM} /V _{RRM}	400 to 600	V	
I _{GT}	200	μА	

Applications

Typical applications are capacitive discharge systems for strobe lights and gas engine ignition. Also controls for power tools, home/brown goods and white goods appliances.

Additional Information

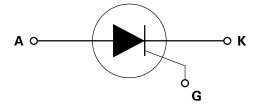






Samples

Schematic Symbol



Absolute Maximum Ratings — Sensitive SCRs

Symbol	Parameter Test Conditions		Value	Unit
I _{T(RMS)}	RMS on-state current	T _C = 40°C	1.5	А
I _{T(AV)}	Average on-state current	$T_{\rm C} = 40^{\circ} \rm C$	0.95	А
	Pools non ronotitivo austro austront	single half cycle; f = 50Hz; T _J (initial) = 25°C	16	۸
I _{TSM}	Peak non-repetitive surge current	single half cycle; $f = 60Hz$; T_J (initial) = 25°C	20	А
l²t	l²t Value for fusing	$t_p = 8.3 \text{ ms}$	1.6	A ² s
di/dt	Critical rate of rise of on-state current $f = 60 \text{ Hz}$; $T_J = 110^{\circ}\text{C}$		50	A/µs
I _{GM}	Peak gate current T _J = 110°C		1	А
P _{G(AV)}	Average gate power dissipation $T_J = 110$ °C		0.1	W
T _{stg}	Storage temperature range		-40 to 150	°C
T	Operating junction temperature range		-40 to 110	°C

Teccor® brand Thyristors 1.5 Amp Sensitive SCRs

Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Test Conditions	Value	Unit		
I _{GT}	V - 6V P - 100 O		MAX.	200	μΑ
V _{GT}	$V_D = 6V; R_L = 100 \Omega$		MAX.	0.8	V
dv./d+	V V D 410		MIN.	40	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
dv/dt	$V_D = V_{DRM}$; $R_{GK} = 1k\Omega$	600V	IVIIIN.	30	V/µs
V _{GD}	$V_{D} = V_{DRM}$; $R_{L} = 3.3 \text{ k}\Omega$; $T_{J} = 110 ^{\circ}\text{C}$		MIN.	0.25	V
V _{GRM}	$I_{GR} = 10\mu A$		MIN.	6	V
I _H	$I_{T} = 200 \text{mA} \text{ (initial)}$		MAX.	5	mA
t _q	(1)		MAX.	50	μs
t _{gt}	$I_{g} = 2 \times I_{gT}$; PW = 15 μ s; $I_{T} = 3A$		TYP.	20	μs

⁽¹⁾ $I_r = 1A$; $t_n = 50\mu s$; $dv/dt = 5V/\mu s$; $di/dt = -10A/\mu s$

Static Characteristics

Symbol		Test Condit	Value	Unit		
V _{TM}	I _T = 3	3A; t _p = 380 μs		1.5	V	
		T 0500	400V		1	
$I_{DRM} / I_{RRM} \qquad \qquad V_{DRM} = V_{RRM} $	$T_J = 25^{\circ}C$	600V	MAX.	2	μΑ	
	T ₁ = 110°C			100		

Thermal Resistances

Symbol	Parameter	Value	Unit
$R_{\theta(J-C)}$	Junction to case (AC)	50	°C/W
$R_{\theta(J-A)}$	Junction to ambient	160	°C/W



Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

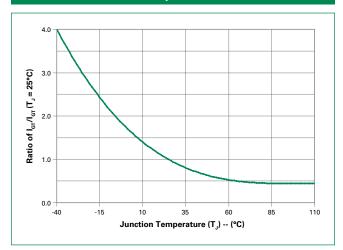


Figure 3: Normalized DC Holding Current vs. Junction Temperature

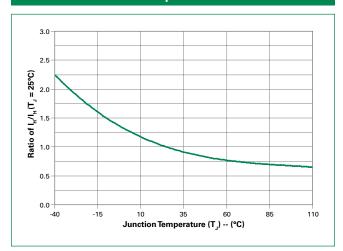
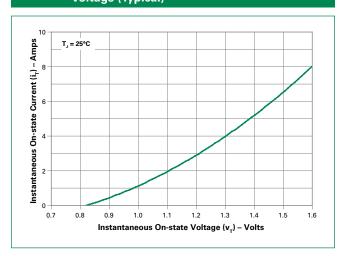


Figure 5: On-State Current vs. On-State Voltage (Typical)



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Revised: 12/14/14

Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

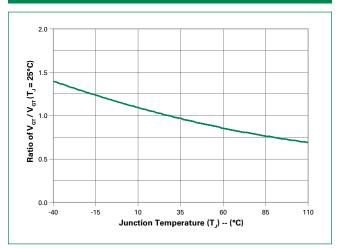


Figure 4: Normalized DC Latching Current vs. Junction Temperature

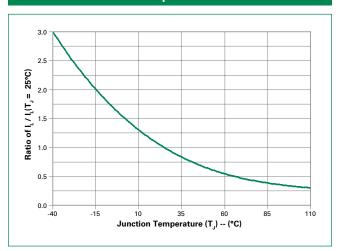


Figure 6: Power Dissipation (Typical) vs. RMS On-State Current

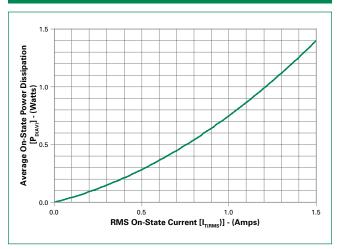




Figure 7: Maximum Allowable Case Temperature vs. RMS On-State Current

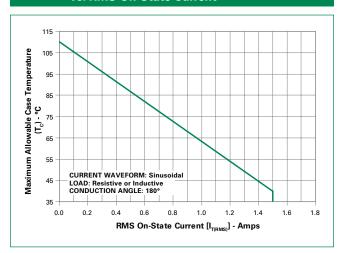


Figure 9: Maximum Allowable Ambient Temperature vs. RMS On-State Current

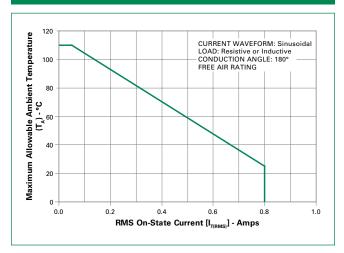


Figure 11: Peak Repetitive Capacitor Discharge Current

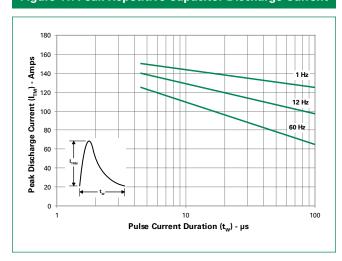


Figure 8: Maximum Allowable Case Temperature vs. Average On-State Current

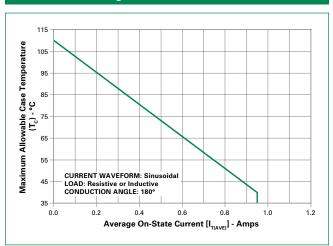


Figure 10: Maximum Allowable Ambient Temperature vs. Average On-State Current

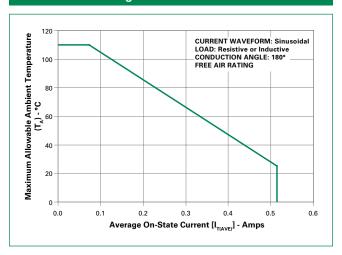


Figure 12: Peak Repetitive Sinusoidal Pulse Current

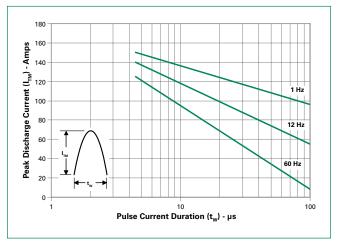
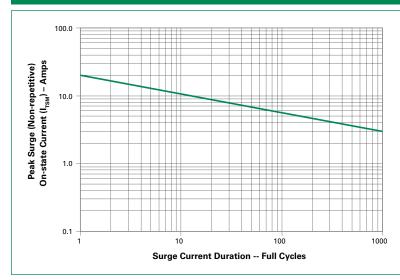




Figure 13: Surge Peak On-State Current vs. Number of Cycles



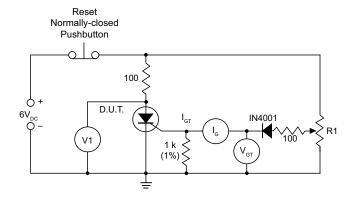
SUPPLY FREQUENCY: 60 Hz Sinusoidal LOAD: Resistive

RMS On-State Current: $[I_{T(RMS)}]$: Maximum Rated Value at Specified Case Temperature

Notes:

- 1. Gate control may be lost during and immediately following surge current interval.
- 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

Figure 14: Simple Test Circuit for Gate Trigger Voltage and Current



Note: V1 - 0V to 10V dc meter V_{GT} — 0 V to 1 V dc meter I_G — 0 mA to 1 mA dc milliammeter R1 — 1 k potentiometer

To measure gate trigger voltage and current, raise gate voltage (V_{GT}) until meter reading V1 drops from 6 V to 1 V. Gate trigger voltage is the reading on $V_{\rm GT}$ just prior to V1 dropping. Gate trigger current $I_{\rm GT}$ Can be computed from

$$I_{GT} = I_{G}^{-} \frac{V_{GT}}{1000} Amps$$

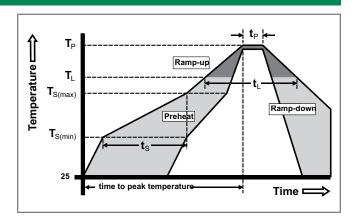
where I_G is reading (in amperes) on meter just prior to V1 dropping

Note: I_{GT} may turn out to be a negative quantity (trigger current flows out from gate lead). If negative current occurs, $I_{\rm GT}$ value is not a valid reading. Remove 1 k resistor and use $I_{\rm G}$ as the more correct $I_{\rm GT}$ value. This will occur on 12 µA gate products.

Teccor® brand Thyristors 1.5 Amp Sensitive SCRs

Soldering Parameters

Reflow Co	ndition	Pb – Free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ra	amp up rate (LiquidusTemp) k	5°C/second max	
T _{S(max)} to T _L - Ramp-up Rate		5°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
hellow	-Temperature (t _L)	60 – 150 seconds	
PeakTemp	erature (T _P)	260+0/-5 °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-down Rate		5°C/second max	
Time 25°C to peakTemperature (T _p)		8 minutes Max.	
Do not exc	ceed	280°C	



Physical Specifications

Terminal Finish	100% Matt Tin-plated/Pb-free Solder Dipped
Body Material	UL recognized epoxy meeting flammability classification 94V-0
Lead Material	Copper Alloy

Design Considerations

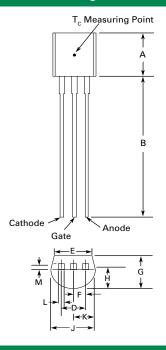
Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Thermal Shock	MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwell- time at each temperature; 10 sec (max) transfer time between temperature
Autoclave	EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E



Dimensions - TO-92 (E Package)



Dimension	Inches		Mill	imeters
Dimension	Min	Max	Min	Max
А	0.176	0.196	4.47	4.98
В	0.500		12.70	
D	0.095	0.105	2.41	2.67
E	0.150		3.81	
F	0.046	0.054	1.16	1.37
G	0.135	0.145	3.43	3.68
Н	0.088	0.096	2.23	2.44
J	0.176	0.186	4.47	4.73
K	0.088	0.096	2.23	2.44
L	0.013	0.019	0.33	0.48
М	0.013	0.017	0.33	0.43

All leads insulated from case. Case is electrically nonconductive.

Product Selector

Part Number	Voltage				Gate Sensitivity	Time	Pookogo
rait Nullibei	400V	600V	800V	1000V	Gate Sensitivity	Туре	Package
TCR22-6	X				200μΑ	Sensitive SCR	TO-92
TCR22-8		X			200μΑ	Sensitive SCR	TO-92

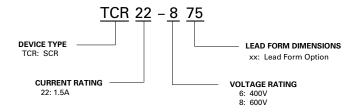
Note: x = Voltage

Packing Options

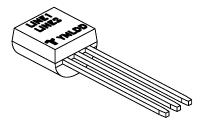
Part Number	Marking	Weight	Packing Mode	Base Quantity
TCR22-x	TCR22-x	0.19 g	Bulk	2000
TCR22-xRP	TCR22-x	0.19 g	Reel Pack	2000
TCR22-xAP	TCR22-x	0.19 g	Ammo Pack	2000

Note: x = Voltage

Part Numbering System



Part Marking System

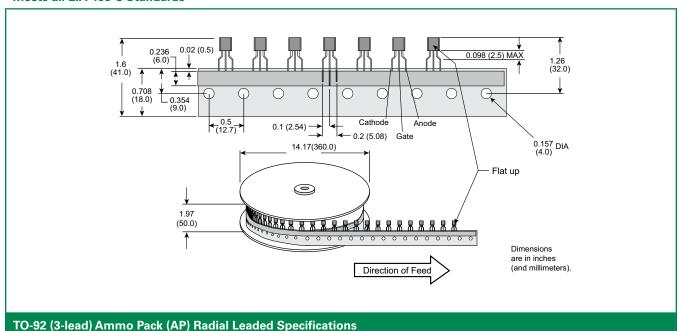


Line1 = Littelfuse Part Number
Line2 = continuation...Littelfuse Part Number
Y = Last Digit of Calendar Year
M = Letter Month Code (A-L for Jan-Dec)
L = Location Code
DD = Calendar Date

Teccor® brand Thyristors 1.5 Amp Sensitive SCRs

TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards



Meets all EIA-468-C Standards

